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- Inputs Are TTL-Voltage Compatible
- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

description

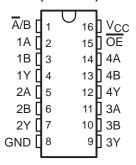
These quadruple 2-line to 1-line data selectors/multiplexers are designed for 4.5-V to $5.5\text{-V}\ \text{V}_{CC}$ operation.

The 'AHCT258 devices are designed to multiplex signals from 4-bit data sources to 4-output data lines in bus-organized systems. The 3-state outputs do not load the data lines when the output-enable (\overline{OE}) input is at the high logic level.

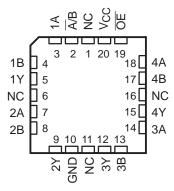
To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHCT258 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHCT258 is characterized for operation from -40°C to 85°C.

SN54AHCT258...J OR W PACKAGE SN74AHCT258...D, DB, DGV, N, OR PW PACKAGE (TOP VIEW)



SN54AHCT258...FK PACKAGE (TOP VIEW)



NC - No internal connection

FUNCTION TABLE

	INPU	OUTPUT		
OE	A/B	Α	В	Υ
Н	Х	Х	Х	Z
L	L	L	X	Н
L	L	Н	X	L
L	Н	Χ	L	Н
L	Н	Χ	Н	L



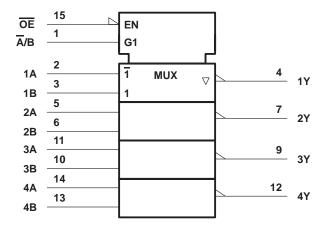
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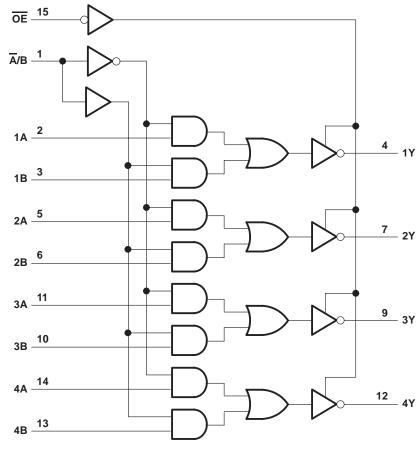
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.

logic diagram (positive logic)



Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		0.5 V to 7 V
Input voltage range, V _I (see Note 1)		0.5 V to 7 V
Output voltage range, VO (see Note 1)		. -0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$)		–20 mA
Output clamp current, IOK (VO < 0 or VO > VCO	c)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	·····	±25 mA
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ_{JA} (see Note 2):	: D package	113°C/W
•	DB package	131°C/W
	DGV package	180°C/W
	N package	
	PW package	
Storage temperature range, T _{sto}	. •	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions (see Note 3)

		SN54AHCT258		ICT258 SN74AHCT258		
		MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
٧ _I	Input voltage	0	5.5	0	5.5	V
٧o	Output voltage	0	VCC	0	VCC	V
IOH	High-level output current		-8		-8	mA
loL	Low-level output current		8		8	mA
Δt/Δν	Input transition rise or fall time		20		20	ns/V
T _A	Operating free-air temperature	- 55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	ARAMETER TEST CONDITIONS		T _A = 25°C			SN54AHCT258		SN74AHCT258		UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
V	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4		.,
VOH	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		V
	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
VOL	I _{OL} = 8 mA				0.36		0.44		0.44	\ \ \
lį	V _I = V _{CC} or GND	5.5 V			±0.1		±1		±1	μΑ
^I CC	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
ΔI _{CC} †	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5	mA
loz	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μΑ
Ci	V _I = V _{CC} or GND	5 V			·					pF

[†] This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

			SN5	SN54AHCT258											
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$ \begin{array}{c c} \text{LOAD} & \hline & T_{\text{A}} = 25^{\circ}\text{C} \\ \hline & \text{MIN} & \text{TYP} & \text{MAX} \\ \end{array} $		1 1 1 25°C		MAX	UNIT							
	(01)	(0011 01)			TYP	MAX	IVIIIN	WAX							
^t PLH*	A or B	Y	C _L = 15 pF						ns						
t _{PHL} *	AOIB	·	OL = 13 pi						113						
^t PLH*	Ā/B	Y	C _L = 15 pF						ns						
tPHL*	A/D	ı	OL = 13 pi						113						
^t PZH*	ŌĒ	Υ	C _L = 15 pF						ns						
^t PZL*	OE	·	OL = 13 bi						113						
^t PHZ*	ŌĒ	Y	C _L = 15 pF						ns						
tPLZ*	OE	I	OL = 13 pr						115						
t _{PLH}	A or B	Y	C _L = 50 pF						ns						
^t PHL	AOIB	I	OL = 30 pr						115						
^t PLH	_ A∕B	Y	C _L = 50 pF						ns						
^t PLH	A/B	ı	OL = 30 pr						115						
^t PZH	ŌĒ	Y	C _L = 50 pF						ns						
tPZL	UE	ſ	r	ī	ī	ī	ī	ĭ	OL = 50 PF						115
^t PHZ	ŌĒ	Y	C _L = 50 pF						ns						
tPLZ	OE .	ľ	OL = 50 pr						115						

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

				SN74AHCT258					
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD T _A = 25°C		;	MIN	MAX	UNIT	
	(5.7)	(3011 01)		MIN	TYP	MAX	IVIIIV	IVIAA	
t _{PLH}	A or B	Y	C _L = 15 pF						ns
tPHL	AOIB	•	OL = 10 pi						113
tPLH	_ Ā/B	Y	C _L = 15 pF						ns
tPHL	A/D	'	OL = 10 pi						113
^t PZH	ŌĒ	Y	C _L = 15 pF						ns
t _{PZL}	OE .		OL = 10 pi						
^t PHZ	ŌĒ	Y	C _L = 15 pF						ns
tPLZ	OE .	'	OL = 10 pi						113
tPLH	A or B	Y	C _L = 50 pF						ns
tPHL	AOIB	'	OL = 30 pi						113
tPLH	_ Ā/B	Y	C _L = 50 pF						ns
^t PLH	A/D	'	OL = 30 pi						113
^t PZH	ŌĒ	Y	C _L = 50 pF						ns
^t PZL	OE .	•	OL - 00 bi						110
^t PHZ	ŌĒ	Y	C _L = 50 pF						ns
tPLZ	OL .	1	OL = 30 pi						113

noise characteristics V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 4)

PARAMETER		SN7	UNIT		
	FARAWETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}				V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}				V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}				V
V _{IH(D)}	High-level dynamic input voltage				V
V _{IL(D)}	Low-level dynamic input voltage				V

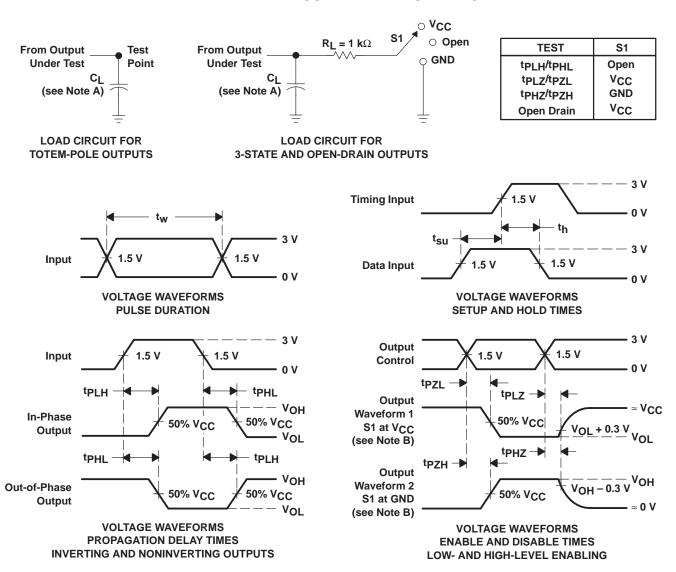
NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER		ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz		pF

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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